



# 6-Pin DIP Zero-Cross **Optoisolators Triac Driver Output** (250 Volts Peak)

The MOC3031, MOC3032 and MOC3033 devices consist of gallium arsenide infrared emitting diodes optically coupled to a monolithic silicon detector performing the function of a Zero Voltage crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 115 Vac lines, such as teletypewriters, CRTs, printers, motors, solenoids and consumer appliances, etc.

- · Simplifies Logic Control of 115 Vac Power
- Zero Voltage Crossing
- dv/dt of 2000 V/μs Typical, 1000 V/μs Guaranteed
- . To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.

## Recommended for 115 Vac(rms) Applications:

- Solenoid/Valve Controls
- Lighting Controls
- Static Power Switches
- AC Motor Drives

- Temperature Controls
- E.M. Contactors
- AC Motor Starters
- Solid State Relays

PD

150

1.76

mW

mW/°C

Rating	Symbol	Value	Unit	
NFRARED LED				
Reverse Voltage	VR	3	Voits	
Forward Current Continuous	l <sub>F</sub>	60	mA mW	
Total Power Dissipation @ TA = 25°C Negligible Power in Output Driver Derate above 25°C	PD	120 1.41		
OUTPUT DRIVER				
Off-State Output Terminal Voltage	VDRM	250	Volts	
Peak Repetitive Surge Current	ITSM	1	Α	

Derate above 25°C	
TOTAL DEVICE	

(PW = 100 μs, 120 pps) Total Power Dissipation @ TA = 25°C

Isolation Surge Voltage <sup>(1)</sup> (Peak ac Voltage, 60 Hz, 1 Second Duration)	Viso	7500	Vac(pk)
Total Power Dissipation @ TA = 25°C Derate above 25°C	PD	250 2.94	mW mW/°C
Junction Temperature Range	TJ	-40 to +100	•0
Amblent Operating Temperature Range(2)	TA	-40 to +85	°C
Storage Temperature Range <sup>(2)</sup>	T <sub>stg</sub>	-40 to +150	°C
Soldering Temperature (10 s)	Tı	260	°C

- 1. Isolation surge voltage, V<sub>ISO</sub>, is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
- 2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions. Preferred devices are Motorola recommended choices for future use and best overall value.

## (Replaces MOC3030/D)

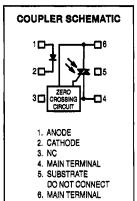
# MOC3031 [IFT = 15 mA Max] **MOC3032** [IFT = 10 mA Max] MOC3033\* [IFT = 5 mA Max1

STYLE 6 PLASTIC

\*Motorola Preferred Device



STANDARD THRU HOLE **CASE 730A-04** 



## MOC3031 MOC3032 MOC3033

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
NPUT LED	•		•	•	
Reverse Leakage Current (V <sub>R</sub> = 3 V)	IR		0.05	100	μА
Forward Voltage (IF = 30 mA)	VF	_	1.3	1.5	Volts
OUTPUT DETECTOR (IF = 0 unless otherwise noted)	<u> </u>	<del>'</del>			
Leakage with LED Off, Either Direction (Rated V <sub>DRM</sub> <sup>(1)</sup> )	IDRM1		10	100	nA
Peak On-State Voltage, Either Direction (ITM = 100 mA Peak)	V™		1.8	3	Volts
Critical Rate of Rise of Off-State Voltage	dv/dt	1000	2000	_	V/µ8
COUPLED					
LED Trigger Current, Current Required to Latch Output (Main Terminal Voltage = 3 V(2))  MOC3031  MOC3032  MOC3033	lFT	=	=	15 10 5	mA
Holding Current, Either Direction	İΗ		250		μА
Isolation Voltage (f = 60 Hz, t = 1 sec)	Viso	7500		_	Vac(pk)
ZERO CROSSING	•				
Inhibit Voltage (IF = Rated IFT, MT1-MT2 Voltage above which device will not trigger.)	VIH	_	5	20	Volts
Leakage in Inhibited State (IF = Rated IFT, Rated VDRM, Off State)	IDRM2	_	_	500	μА

<sup>1.</sup> Test voltage must be applied within dv/dt rating.

# TYPICAL ELECTRICAL CHARACTERISTICS TA = 25°C

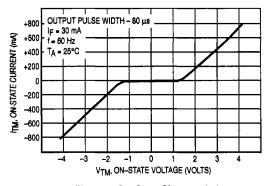


Figure 1. On-State Characteristics

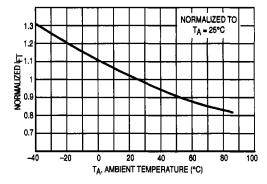


Figure 2. Trigger Current versus Temperature

<sup>2.</sup> All devices are guaranteed to trigger at an IF value less than or equal to max IFT. Therefore, recommended operating IF lies between max IFT (15 mA for MOC3031, 10 mA for MOC3032, 5 mA for MOC3033) and absolute max IF (60 mA).

# MOC3031 MOC3032 MOC3033

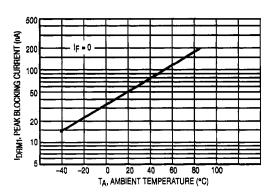


Figure 3. IDRM1, Peak Blocking Current versus Temperature

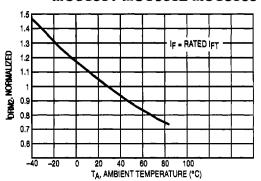


Figure 4. IDRM2, Leakage in inhibit State versus Temperature

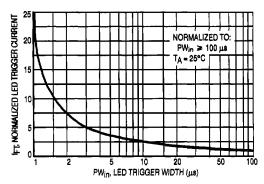
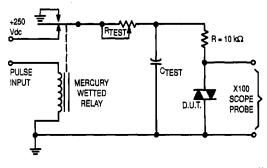


Figure 5. LED Current Required to Trigger versus LED Pulse Width



- The mercury wetted relay provides a high speed repeated pulse to the D.U.T.
- 100x scope probes are used, to allow high speeds and voltages.
- 3. The worst-case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable RTEST allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. τ<sub>RC</sub> is measured at this point and recorded.

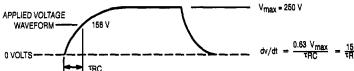
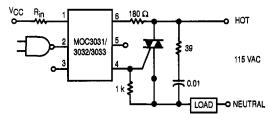


Figure 6. Static dv/dt Test Circuit

# MOC3031 MOC3032 MOC3033



\* For highly inductive loads (power factor < 0.5), change this value to 360 ohms.

Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

 $R_{In}$  is calculated so that IF is equal to the rated IFT of the part, 5 mA for the MOC3033, 10 mA for the MOC3032, or 15 mA for the MOC3031. The 39 ohm resistor and 0.01  $\mu F$  capacitor are for snubbling of the triac and may or may not be necessary depending upon the particular triac and load used.

Figure 7. Hot-Line Switching Application Circuit

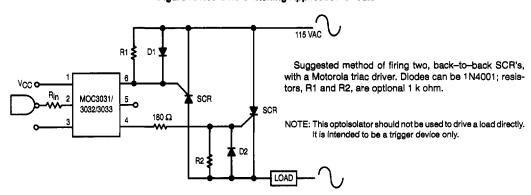


Figure 8. Inverse-Parallel SCR Driver Circuit